

# 3A 27V Synchronous Buck Converter

## Description

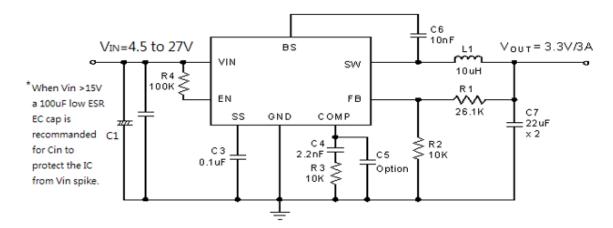
The HG1484 is a monolithic synchronous buck regulator. The device integrates 90 m $\Omega$ MOSFETS that provide 3A continuous load current over a wide operating input voltage of 4.5V to 27V. Current mode control provides fast transient response and cycle- by-cycle current limit. An adjustable soft-start prevents inrush current at turn on.

### Features

- 3A Output Current
- Wide 4.5V to 27V Operating Input Range
- Fixed 340KHZ Frequency
- Integrated Power MOSFET switches
- Output Adjustable from 0.925V to 0.8Vin Up to 93% Efficiency
- Programmable Soft-Start
- Stable with Low ESR Ceramic Output Capacitors
- Cycle by Cycle Over Current Protection
- Short Circuit Protection
- Input Under Voltage Lockout
- Package : ESOP-8L

### **Applications**

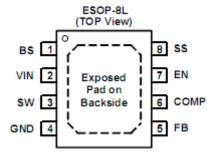
- Distributed Power Systems
- Networking Systems
- FPGA, DSP, ASIC Power Supplies
- Green Electronics/ Appliances
- Notebook Computers



### **Typical Application Circuit**



# **Pin Assignments**

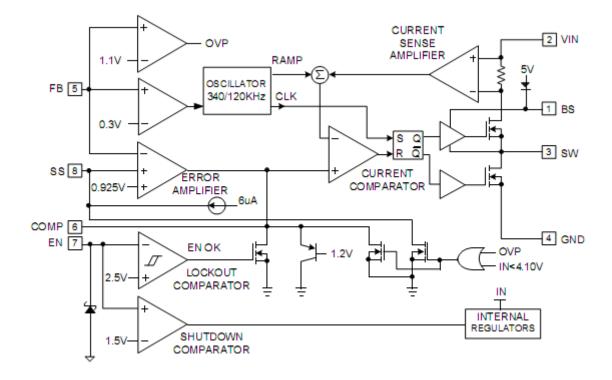


# **Pin Descriptions**

Pin Number	Name	Description
	DO	Bootstrap. This pin acts as the positive rail for the high-side switch's gate
1	BS	driver. Connect a 0.01uF capacitor between BS and SW.
2	VIN	Input Supply. Bypass this pin to GND with a low ESR capacitor. See Input
2	VIIN	Capacitor in the Application Information section.
3	SW	Switch Output. Connect this pin to the switching end of the inductor.
4	GND	Ground.
F	FR	Feedback Input. The voltage at this pin is regulated to 0.925V.Connect to the
5		resistor divider between output and ground to set
6	COMP	Compensation Pin. See Stability Compensation in the Application Information
0		section.
		Enable Input. When higher than 2.7V, this pin turns the IC on. When lower
7	EN	than 1.1V, this pin turns the IC off. Output voltage is discharged when the IC
		is off. This pin should not be left open. Recommend to put
		Soft-Start Control Input. SS controls the soft-start period. Connect a capacitor
8	SS	from SS to GND to set the soft-start period. A 0.1uF capacitor sets the
		soft-start period to 13ms. To disable the soft-start
	Exposed Pad	Exposed Pad. Need to connect to GND pin.



### **Block Diagram**



### **Absolute Maximum Ratings**

Parameter	Value	Unit
Input Supply Voltage	-0.3 to 30	V
SW Voltage	-0.3 to VIN + 0.3	V
BS Voltage	VSW – 0.3 to VSW + 6	V
EN, FB, COMP Voltage	-0.3 to 5	V
Continuous SW Current	Internally limited	А
Junction to Ambient Thermal Resistance (θ <sub>JA</sub> ) (Test on Approximately 3 in <sup>2</sup> Copper Area 1oz copper FR4 board)	20	°C/W
Junction to Ambient Case Resistance ( $\theta_{JC}$ )	10	°C/W
SOP-8L Power Dissipation	Internally limited	W
Maximum Junction Temperature	150	°C
Storage Temperature Range	-65 to 150	°C
Moisture Sensitivity (MSL)	Please refer the MSL label on the IC package	

(Note: Exceeding these limits may damage the device. Even the duration of exceeding is very short.



1

Exposure to absolute maximum rating conditions for long periods may affect device reliability.)

# **Recommended Operating Conditions**

Parameter	Min	Мах	Unit
Input Supply Voltage	4.5	27 <sup>(1)</sup>	V
Operating Junction Temperature	-20	+125 <sup>(2)</sup>	°C

(Note (1): Operating the IC over this voltage is very easy to cause over voltage condition to VIN pin, SW pin, BS pin & EN pin)

(Note (2): If the IC experienced OTP, then the temperature may need to drop to <125 degree C to let the IC recover.)

## **Electrical Characteristics**

(VIN = 12V, TA= 25°C unle	ss otherwise specified.)
---------------------------	--------------------------

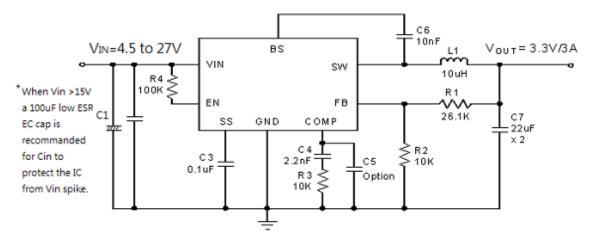
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Feedback Voltage	$V_{\text{FB}}$	$4.5V \le VIN \le 27V$	0.900	0.925	0.950	V
Feedback Overvoltage Threshold				1.1		V
High-Side Switch-On Resistance*				90		mΩ
Low-Side Switch-On Resistance*				70		mΩ
High-Side Switch Leakage		$V_{EN} = 0V, V_{SW} = 0V$		0.1	10	uA
Upper Switch Current Limit*		Minimum Duty Cycle	3.8	4.5		А
Lower Switch Current Limit*		From Drain to Source		1.2		А
COMP to Current Sense Limit Transconductance	G <sub>CS</sub>			5.2		A/V
Error Amplifier Transconductance	G <sub>EA</sub>	$\Delta_{ICOMP} = \pm 10 uA$		900		uA/V
Error Amplifier DC Gain*	A <sub>VEA</sub>			400		V/V
Switching Frequency	f <sub>SW</sub>		300	340	380	KHz
Short Circuit Switching Frequency		$V_{FB} = 0$		100		KHz
Minimum Duty Cycle*	D <sub>min</sub>		7.5			%
Maximum Duty Cycle	D <sub>max</sub>			92		%
EN Shutdown Threshold Voltage		V <sub>EN</sub> Rising	1.1	1.4	2	V
EN Shutdown Threshold Voltage Hysteresis				180		mV
EN Lockout Threshold Voltage			2.2	2.5	2.7	V
EN Lockout Hysteresis				150		mV



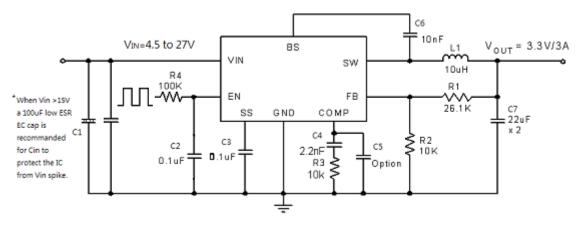
Supply Current in Shutdown		V <sub>EN</sub> = 0		0.3	3.0	uA
IC Supply Current in Operation		$V_{\text{EN}} = 3V, \ V_{\text{FB}} = 1.0V$		1.3	1.5	mA
Input UVLO Threshold Rising	UVLO	V <sub>EN</sub> Rising	3.80	4.0	4.40	V
Input UVLO Threshold Hysteresis				150		mV
Soft-start Current		$V_{SS} = 0V$		6		uA
Soft-start Period		$C_{SS} = 0.1 \mu F$		13		mS
Thermal Shutdown Temperature*		Hysteresis =25°C		155		°C

Note: \* Guaranteed by design, not tested

# **Application Description**



#### HG1484 application circuit, 3.3V/3A output



HG1484 application circuit, 3.3V/3A output with EN function Note: C2 is required for separate EN signal.



#### **Output Voltage Setting**

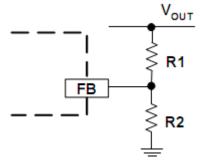


Figure1. Output Voltage Setting

Figure 1 shows the connections for setting the output voltage. Select the proper ratio of the two feedback resistors R1 and R2 based on the output voltage. Typically, use R2  $\approx$  10K $\Omega$  and determine R1 from the following equation:

$$R1 = R2 \left( \frac{V_{OUT}}{0.925 \text{V}} \cdot 1 \right) \tag{1}$$

Table1 - Recommended Resistance Values

VOUT	R1	R2
1.0V	1.0 KΩ	12 KΩ
1.2V	3.0 KΩ	10 KΩ
1.8V	9.53 KΩ	10 KΩ
2.5V	16.9 KΩ	10 KΩ
3.3V	26.1 KΩ	10 KΩ
5V	44.2 KΩ	10 KΩ
12V	121 KΩ	10 KΩ

#### **Inductor Selection**

The inductor maintains a continuous current to the output load. This inductor current has a ripple that is dependent on the inductance value: higher inductance reduces the peak-to-peak ripple current. The tradeoff for high inductance value is the increase in inductor core size and series resistance, and the reduction in current handling capability. In general, select an inductance value L based on the ripple current requirement:

$$L = \frac{V_{OUT} \bullet (V_{IN} - V_{OUT})}{V_{IN} f_{SW} I_{OUTMAX} K_{RIPPLE}}$$
(2)

Where  $V_{IN}$  is the input voltage,  $V_{OUT}$  is the output voltage,  $f_{SW}$  is the switching frequency, and  $I_{OUTMAX}$  is the maximum output current, and  $K_{RIPPLE}$  is the ripple factor. Typically, choose  $K_{RIPPLE} = ~ 30\%$  to correspond to the peak-to-peak ripple current being ~30% of the maximum output current. With this inductor value, the peak inductor current is  $I_{OUT} \cdot (1 + K_{RIPPLE} / 2)$ . Make sure that this peak inductor current is less than the upper switch current limit. Finally, select the inductor core size so that it



does not saturate at the current limit. Typical inductor values for various output voltages are shown in Table 2.

١	VOUT	1.0V	1.2V	1.5V	1.8V	2.5V	3.3V	5V	9V
	L	4.7uH	4.7uH	10uH	10uH	10uH	10uH	10uH	22uH
	Table2 Typical Inductor Values								

#### **Input Capacitor**

The input capacitor needs to be carefully selected to maintain sufficiently low ripple at the supply input of the converter. A low ESR Electrolytic (EC) capacitor is highly recommended. Since large current flows in and out of this capacitor during switching, its ESR also affects efficiency.

When EC cap is used, the input capacitance needs to be equal to or higher than 100uF. The RMS ripple current rating needs to be higher than 50% of the output current. The input capacitor should be placed close to the VIN and GND pins of the IC, with the shortest traces possible. The input capacitor can be placed a little bit away if a small parallel 0.1uF ceramic capacitor is placed right next to the IC. When  $V_{IN}$  is >15V, pure ceramic Cin (\* no EC cap) is not recommended. This is because the ESR of a ceramic cap is often too small, pure ceramic Cin will work with the parasite inductance of the input trace and forms a  $V_{IN}$  resonant tank. When  $V_{IN}$  is hot plug in/out, this resonant tank will boost the Vin spike to a very high voltage and damage the IC.

#### **Output Capacitor**

The output capacitor also needs to have low ESR to keep low output voltage ripple. In the case of ceramic output capacitors, RESR is very small and does not contribute to the ripple. Therefore, a lower capacitance value can be used for ceramic capacitors. In the case of tantalum or electrolytic capacitors, the ripple is dominated by RESR multiplied by the ripple current. In that case, the output capacitor is chosen to have sufficiently low ESR.

For ceramic output capacitors, typically choose two capacitors of about 22 $\mu$ F. For tantalum or electrolytic capacitors, choose a capacitor with less than 50m $\Omega$  ESR.

#### **Optional Schottky Diode**

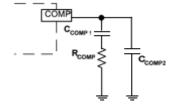
During the transition between high-side switch and low-side switch, the body diode of the low side power MOSFET conducts the inductor current. The forward voltage of this body diode is high. An optional Schottky diode may be paralleled between the SW pin and GND pin to improve overall efficiency. Table 3 lists example Schottky diodes and their Manufacturers.

Vin max	Part Number	Voltage/Current Rating	Vendor
<20V	B130	30V, 1A	
<20V	SK13	30V, 1A	
>20V	B140	40V,1A	
>20V	SK14	40V, 1A	

Table 3-Diode Selection Guid	e
------------------------------	---



#### **Stability Compensation**



 $C_{COMP2}$  is needed only for high ESR output capacitor Figure2. Stability Compensation

The feedback loop of the IC is stabilized by the components at the COMP pin, as shown in Figure 2. The DC loop gain of the system is determined by the following equation:

$$A_{\nu DC} = \frac{0.925 V}{I_{OUT}} A_{\nu EA} G_{COMP}$$
(4)

The dominant pole P1 is due to CCOMP1:

$$f_{P1} = \frac{G_{EA}}{2\pi A_{VEA} C_{COMP1}}$$
(5)

The second pole P2 is the output pole:

$$f_{P2} = \frac{I_{OUT}}{2\pi V_{OUT} C_{OUT}} \tag{6}$$

The first zero Z1 is due to RCOMP and CCOMP1:

$$f_{z_1} = \frac{1}{2\pi R_{COMP} C_{COMP_1}} \tag{7}$$

And finally, the third pole is due to RCOMP and CCOMP2 (if CCOMP2 is used):

$$f_{P3} = \frac{1}{2\pi R_{COMP} C_{COMP2}} \tag{8}$$

The following steps should be used to compensate the IC:

STEP1. Set the crossover frequency at 1/10 of the switching frequency via RCOMP:

$$R_{COMP} = \frac{2\pi V_{OUT} C_{OUT} f_{SW}}{10G_{EA}G_{COMP} \bullet 0.925V}$$
(9)

But limit RCOMP to  $10K\Omega$  maximum. More than  $10 K\Omega$  is easy to cause overshoot at power on. STEP2. Set the zero fZ1 at 1/4 of the crossover frequency. If RCOMP is less than  $10K\Omega$ , the equation for CCOMP is:

$$C_{COM^{p_1}} = \frac{0.637}{R_{COM^p} \times fc} \qquad (F) \quad (10)$$



STEP3. If the output capacitor's ESR is high enough to cause a zero at lower than 4 times the crossover frequency, an additional compensation capacitor CCOMP2 is required. The condition for using CCOMP2 is:

$$\pi \times COUT \times R_{ESR} \times fs \ge 1$$
 (11)

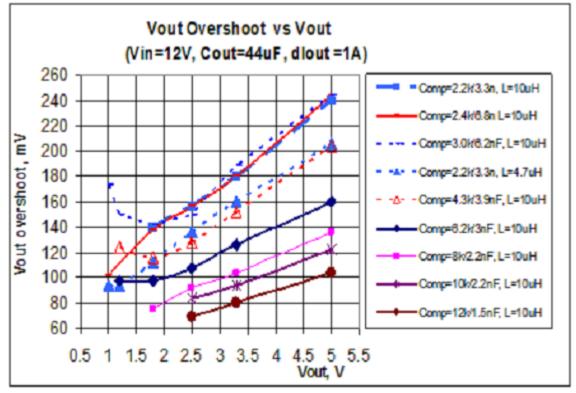
And the proper value for  $C_{\text{COMP2}}$  is:

$$C_{COMP2} = \frac{C_{OUT}R_{ESRCOUT}}{R_{COMP}}$$
(12)

Though CCOMP2 is unnecessary when the output capacitor has sufficiently low ESR, a small value CCOMP2 such as 100pF may improve stability against PCB layout parasitic effects. Table 4 Component Selection Guide for Stability Compensation

Vin Range (V)	Vout(V)	Cout	Rcomp(kΩ)	Ccomp(nF)	Ccomp2(pF)	Inductor(uH)
5 – 12	1.0		2.4	6.8	none	4.7
5 – 15	1.2		3	6.2	none	4.7
5 – 15	1.8	22uF x2 Ceramic	6.2	3	none	10
5 – 15	2.5		8	2.2	none	10
5 – 15	3.3		10	2.2	none	10
7 – 15	5		10	2.2	none	10
5 – 12	1.0					
5 – 15	1.2					
5 – 23	1.8	470uF/	10	10	<u> </u>	10
5 – 27	2.5	6.3V/ 120mΩ	10	10	680	10
5 – 27	3.3					
7 – 27	5					



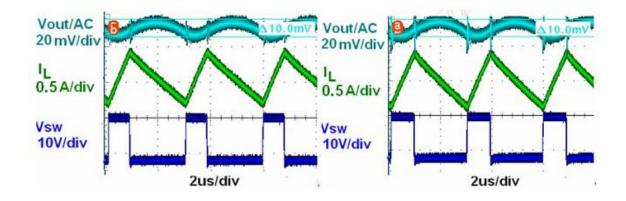


Figur3. Load Transient Testing VS Compensation Value

## **Typical Performance Characteristics**

( $V_{IN}$ =12V, Io=0 mA, Temperature = 25 degree C, unless otherwise specified)

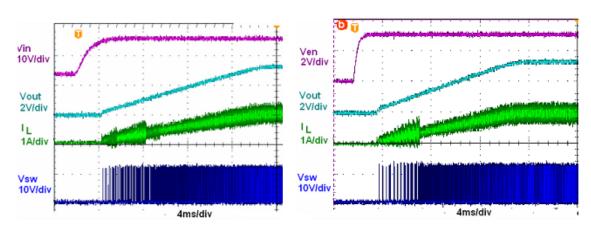
Light Load Operation (No load) V<sub>IN</sub>=12V, lin=8.2 mA, Vout=3,3V Heavy Load Operation (3A Load) VI<sub>N</sub>=12V, Vout=3,3V

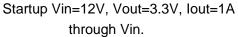


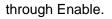
Startup V<sub>IN</sub>=12V, Vout=3.3V, Iout=1A through Vin.

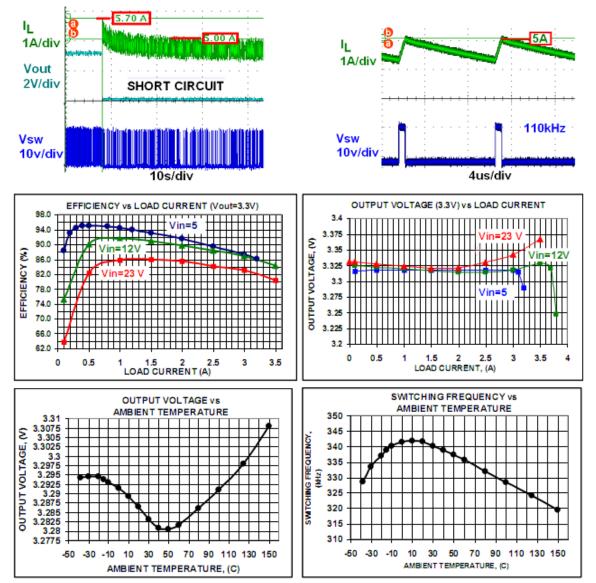
through Enable.



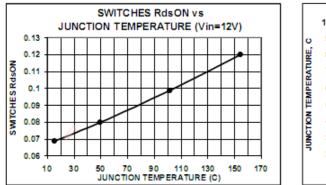


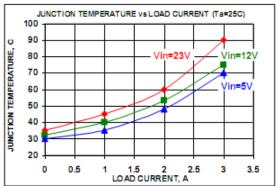














Important statement:

Huaguan Semiconductor Co,Ltd. reserves the right to change the products and services provided without notice. Customers should obtain the latest relevant information before ordering, and verify the timeliness and accuracy of this information.

Customers are responsible for complying with safety standards and taking safety measures when using our products for system design and machine manufacturing to avoid potential risks that may result in personal injury or property damage.

Our products are not licensed for applications in life support, military, aerospace, etc., so we do not bear the consequences of the application of these products in these fields.

Our documentation is only permitted to be copied without any tampering with the content, so we do not accept any responsibility or liability for the altered documents.